

SANYO Semiconductors DATA SHEET

2SK3829-

N-Channel Silicon MOSFET

General-Purpose Switching Device **Applications**

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.
- Motor drive, DC / DC Converter.
- Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		48	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	192	Α
Allowable Power Dissipation	Do		2.5	W
	PD	Tc=25°C	65	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		86	mJ
Avalanche Current *2	IAV		48	Α

^{*1.} V_{DD}=20V, L=50µH, I_{AV}=48A

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			I I a is
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS= ±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =24A	18	30		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=24A, VGS=10V		21	27.5	mΩ
	R _{DS} (on)2	ID=24A, VGS=4V		29	41	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		1780		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		266		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		197		pF

Marking: K3829 Continued on next page.

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^{*2.} L≤50μH, 1 Pulse

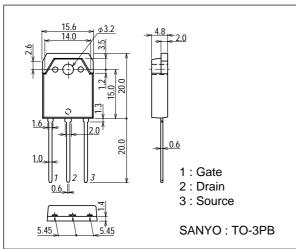
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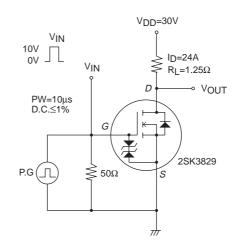
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Oill
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		16.5		ns
Rise Time	t _r	See specified Test Circuit.		180		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		155		ns
Fall Time	tf	See specified Test Circuit.		165		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =48A		40		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =48A		6.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =48A		11.5		nC
Diode Forward Voltage	V _{SD}	I _S =48A, V _{GS} =0		1.08	1.5	V

Package Dimensions

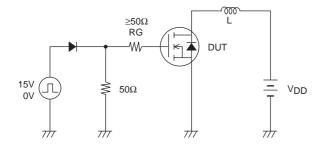
unit : mm 2056A

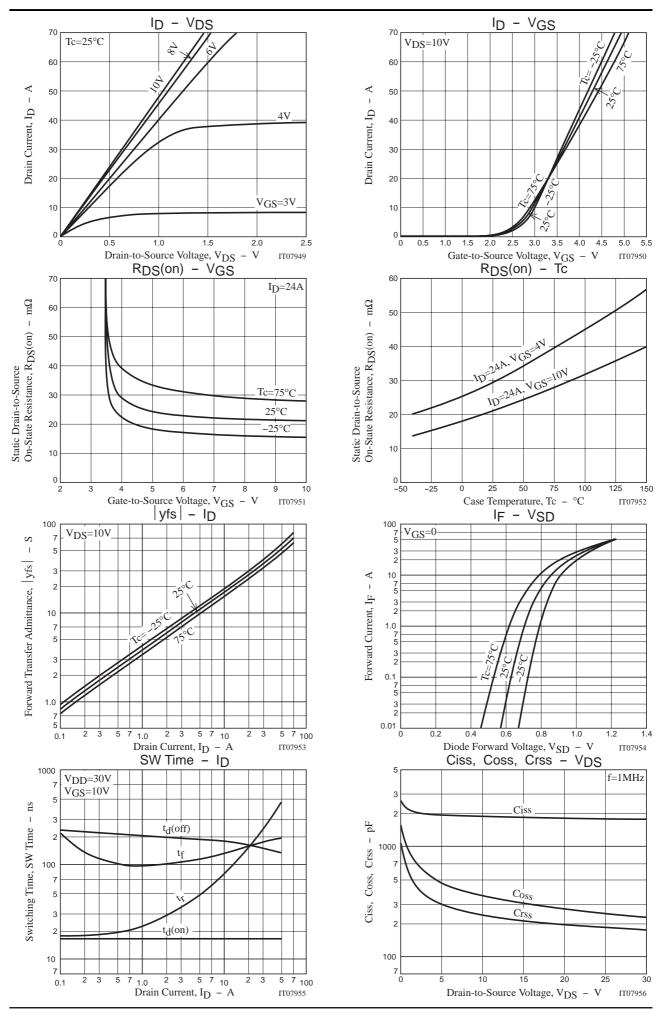


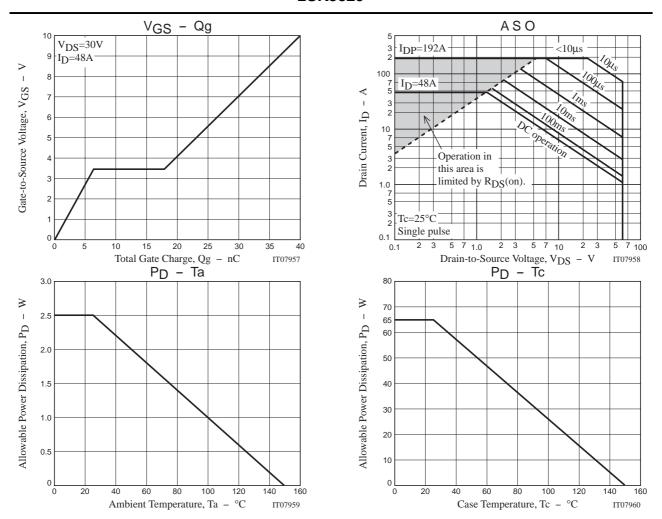
Switching Time Test Circuit



Unclamped Inductive Circuit







Note on usage: Since the 2SK3829 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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